

Vishay Semiconductors

# Medium Power Silicon Rectifier Diodes, (Stud Version), 12 A



DO-203AA (DO-4)

PRODUCT SUMMARY			
I <sub>F(AV)</sub>	12 A		
Package	DO-203AA (DO-4)		
Circuit configuration	Single diode		

### FEATURES

- Voltage ratings from 50 V to 1000 V
- High surge capability
- Low thermal impedance
- High temperature rating
- Can be supplied as JAN and JAN-TX devices in accordance with MIL-S-19500/260
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

Pb
<b>BoHS</b>

COMPLIANT

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I <sub>F(AV)</sub>		12	А	
	T <sub>C</sub>	150	°C	
I <sub>FSM</sub>	50 Hz	230	A	
	60 Hz	240		
l <sup>2</sup> t	50 Hz	260	– A <sup>2</sup> s	
	60 Hz	240		
TJ		-65 to 200	°C	
V <sub>RRM</sub>	Range	50 to 1000	V	

Note

• JEDEC<sup>®</sup> registered values are in bold

### ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	V <sub>R(RMS)</sub> , MAXIMUM RMS REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	V <sub>RM</sub> , MAXIMUM DIRECT REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V
VS-1N1199A	50	35	100	50
VS-1N1200A	100	70	200	100
VS-1N1201A	150	105	300	150
VS-1N1202A	200	140	350	200
VS-1N1203A	300	210	450	300
VS-1N1204A	400	280	600	400
VS-1N1205A	500	350	700	500
VS-1N1206A	600	420	800	600
VS-1N3670A	700	490	900	700
VS-1N3671A	800	560	1000	800
VS-1N3672A	900	630	1100	900
VS-1N3673A	1000	700	1200	1000

Notes

JEDEC registered values are in bold

Basic part number indicates cathode to case; for anode to case, add "R" to part number, e.g., 1N1199RA

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## VS-1N1...A, VS-1N36..A Series

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FORWARD CON	IDUCTION					
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current		I <sub>F(AV)</sub>	180° sinusoidal conduction		12	А
at case temperature					150	°C
	Maximum peak one cycle non-repetitive surge current IFSM Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with rated VRRM applied   Half cycle 50 Hz sine wave or 5 ms rectangular pulse Half cycle 50 Hz sine wave or 5 ms rectangular pulse Following any rated load condition and with rated VRRM applied   Half cycle 50 Hz sine wave or 6 ms rectangular pulse Half cycle 60 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with VRRM applied			condition and with rated	230	A
Maximum peak one cy					240	
					275	
			applied following surge = $0 V$	285		
			t = 10 ms	With rated V <sub>RRM</sub> applied	260	
Maximum I <sup>2</sup> t for fusing	Maximum I <sup>2</sup> t for fusing		t = 8.3 ms	following surge, initial T <sub>J</sub> = 200 °C	240	A <sup>2</sup> s
	Maximum I <sup>2</sup> t for individual device fusing		t = 10 ms	With $V_{RRM} = 0$ V following surge, initial $T_J = 200$ °C	370	
device fusing			t = 8.3 ms		340	
Maximum I²√t for indi device fusing	vidual	l²√t <sup>(1)</sup>	t = 0.1 ms to 10 ms, $V_{RRM}$ =	= 0 V following surge	3715	A²√s
Maximum forward vol	Maximum forward voltage drop		I <sub>F(AV)</sub> = 12 A (38 A peak), T <sub>C</sub> = 25 °C		1.35	V
	V <sub>RRM</sub> = 50 V				3.0	
	V <sub>RRM</sub> = 100 V		$_{\rm V)}^{(2)}$ Maximum rated $\rm I_{F(AV)}$ and $\rm T_{C}$		2.5	mA
	V <sub>RRM</sub> = 150 V				2.25	
	$V_{RRM} = 200 V$				2.0	
	V <sub>RRM</sub> = 300 V				1.75	
Maximum average	$V_{RRM} = 400 V$	I <sub>R(AV)</sub> <sup>(2)</sup>			1.5	
reverse current	$V_{RRM} = 500 V$	'R(AV)			1.25	
	$V_{RRM} = 600 V$				1.0	
	V <sub>RRM</sub> = 700 V				0.9	
	V <sub>RRM</sub> = 800 V	-			0.8	
	V <sub>RRM</sub> = 900 V	-			0.7	
	V <sub>RRM</sub> = 1000 V				0.6	

#### Notes

• JEDEC registered values are in bold

<sup>(1)</sup> I<sup>2</sup>t for time  $t_x = I^2 \sqrt{t} x \sqrt{t_x}$ 

<sup>(2)</sup> Maximum peak reverse current (I<sub>RM</sub>) under same conditions  $\approx 2 \text{ x rated } I_{R(AV)}$ 

PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum operating of storage temperature		T <sub>C</sub> , T <sub>Stg</sub>		-65 to 200	°C	
Maximum internal the resistance, junction to		R <sub>thJC</sub>	DC operation	2.0	°C M/	
Thermal resistance, case to sink		R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.5	°C/W	
	minimum		- Torque applied to nut; non-lubricated threads	1.36 (12)	N ⋅ m (lbf ⋅ in)	
	maximum			1.69 (15)		
Mounting torque	minimum		Townup applied to put lubricated threads	1.07 (9.45)		
	maximum		Torque applied to nut; lubricated threads	1.30 (11.55)		
	minimum		The second	1.17 (10.35)		
	maximum		Torque applied to device case; lubricated threads	1.43 (12.65)		
Approximate weight				7.0	g	
				0.25	oz.	
Case style			JEDEC	DO-203AA (DO-4)		

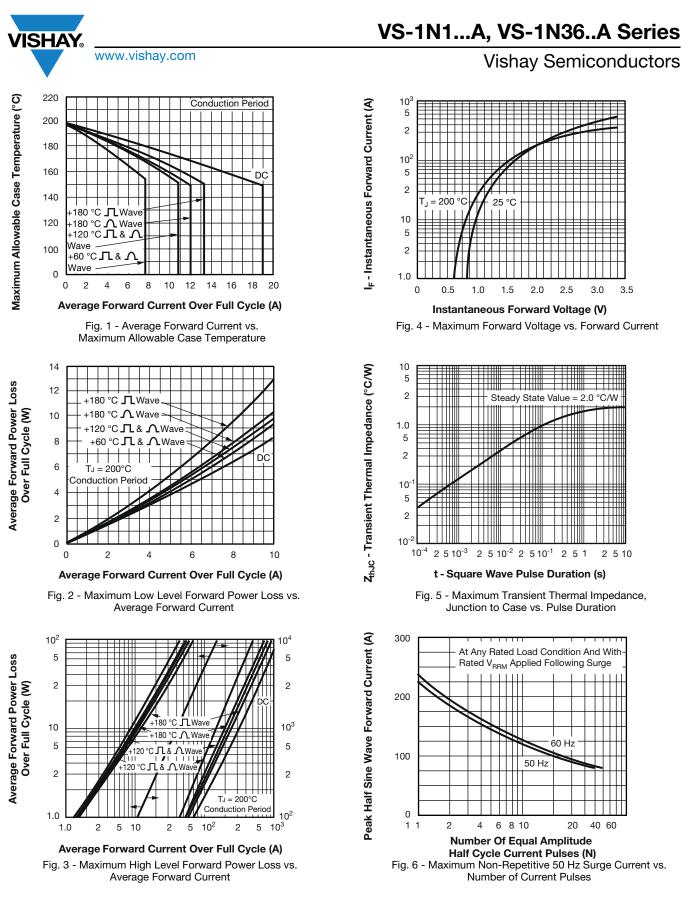
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Revision: 18-May-15

Document Number: 93493

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LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95311	

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R 0.40 R (0.02)

Ø 6.8 (0.27)

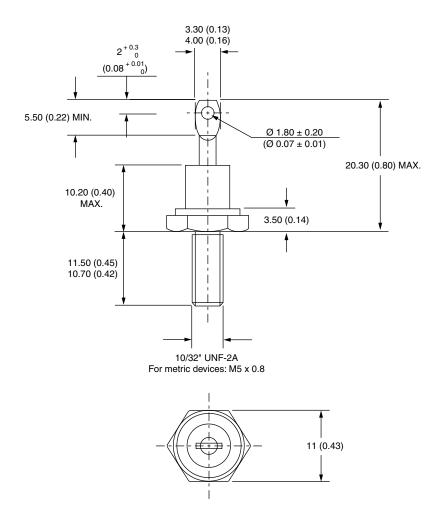
 $0.8 \pm 0.1$ 

 $(0.03 \pm 0.004)$ 



## DO-203AA (DO-4)

### **DIMENSIONS** in millimeters (inches)







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